

COS/MOS INTEGRATED CIRCUIT

4041 UB

HCC/HCF 4041 UB

QUAD TRUE/COMPLEMENT BUFFER

- BALANCED SINK AND SOURCE CURRENT; APPROXIMATELY 4 TIMES STANDARD "B" DRIVE
- EQUALIZED DELAY TO TRUE AND COMPLEMENT OUTPUTS
- QUIESCENT CURRENT SPECIFIED TO 20V FOR HCC DEVICE
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT CURRENT OF 100 nA AT 18V AND 25°C FOR HCC DEVICE
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC TENTATIVE STANDARD NO. 13A, "STANDARD SPECIFICATIONS FOR DESCRIPTION OF "B" SERIES CMOS DEVICES"

The HCC 4041 UB (extended temperature range) and HCF 4041 UB (intermediate temperature range) are monolithic integrated circuits, available in 14-lead dual in-line plastic or ceramic package, ceramic flat package and plastic micropackage.

The HCC/HCF 4041 UB types are quad true/complement buffers consisting of n- and p-channel units having low channel resistance and high current (sourcing and sinking) capability. The HCC/HCF 4041 UB is intended for use as a buffer, line driver, or COS/MOS-to-TTL driver. It can be used as an ultra-low power resistor-network driver for A/D and D/A conversion, as a transmission-line driver, and in other applications where high noise immunity and low-power dissipation are primary design requirements.

ABSOLUTE MAXIMUM RATINGS

| | | |
|------------|------------------------------------------------------------------------------------|-------------------------------|
| V_{DD} * | Supply voltage: HCC types HCF types | -0.5 to 20 V -0.5 to 18 V |
| V_I | Input voltage | -0.5 to V_{DD} +0.5 V |
| I_I | DC input current (any one input) | ± 10 mA |
| P_{tot} | Total power dissipation (per package) | 200 mW |
| | Dissipation per output transistor for $T_{op} =$ full package-temperature range | 100 mW |
| T_{op} | Operating temperature: HCC types HCF types | -55 to 125 °C -40 to 85 °C |
| T_{stg} | Storage temperature | -65 to 150 °C |

* All voltage values are referred to V_{SS} pin voltage

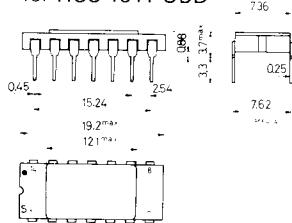
ORDERING NUMBERS:

- HCC 4041 UBD for dual in-line ceramic package
- HCC 4041 UBF for dual in-line ceramic package, frit seal
- HCC 4041 UBK for ceramic flat package
- HCF 4041 UBE for dual in-line plastic package
- HCF 4041 UBF for dual in-line ceramic package, frit-seal
- HCF 4041 UBM for plastic micropackage

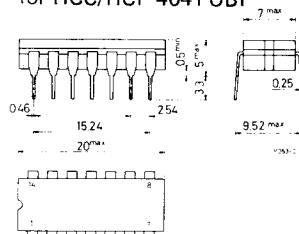
HCC/HCF 4041 UB

MECHANICAL DATA (dimensions in mm)

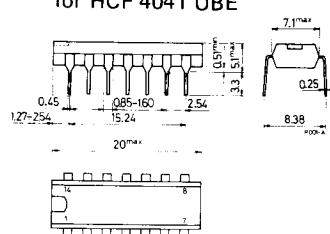
Dual in-line ceramic package for HCC 4041 UBD



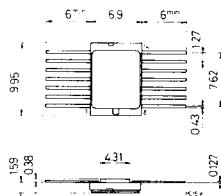
Dual in-line ceramic package for HCC/HCF 4041 UBF



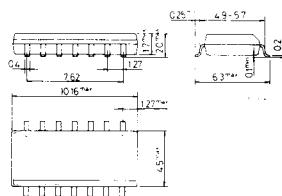
Dual in-line plastic package for HCF 4041 UBE



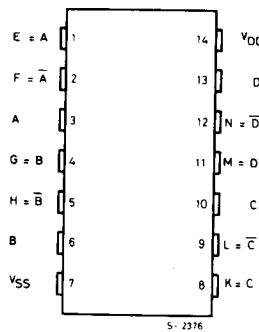
Ceramic flat package for HCC 4041 UBK



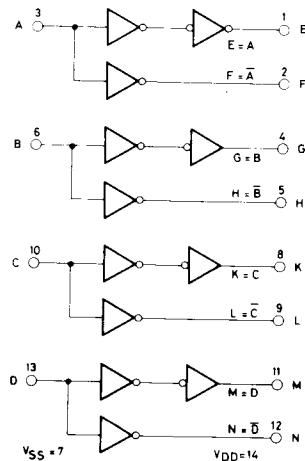
Plastic micropackage for HCF 4041 UBM



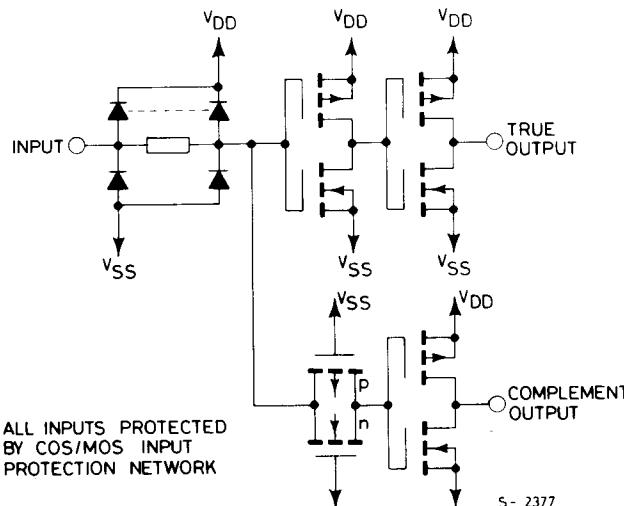
CONNECTION DIAGRAM



FUNCTIONAL DIAGRAM

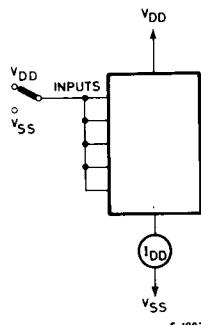


SCHEMATIC DIAGRAM

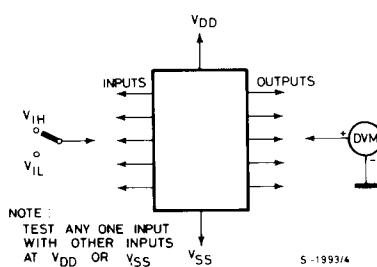


TEST CIRCUITS

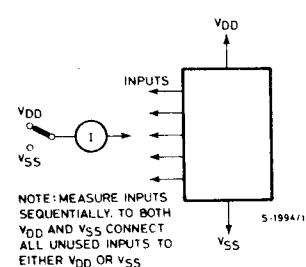
Quiescent device current



Noise immunity



Input leakage current



RECOMMENDED OPERATING CONDITIONS

| | | | |
|-------------------|----------------------------------------------------------------|------------------------------------------|---------------|
| V_{DD} | Supply voltage: HCC types HCF types | 3 to 18 3 to 15 | V V |
| V_I T_{op} | Input voltage Operating temperature: HCC types HCF types | 0 to V_{DD} -55 to 125 -40 to 85 | V °C °C |

STATIC ELECTRICAL CHARACTERISTICS (over recommended operating conditions)

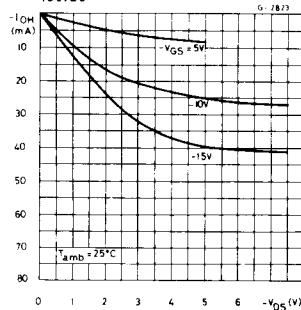
| Parameter | | | Test conditions | | | | Values | | | | | | Unit | |
|----------------------------------|-------------------|------|-----------------|--------------|---------------------------|-----------------|-------------|--------|---------------|-----------|------|--------------|---------|--|
| | | | V_I (V) | V_O (V) | $ I_{OL} $ (μA) | V_{DD} (V) | T_{Low}^* | | $25^\circ C$ | | | T_{High}^* | | |
| | | | | | | | Min. | Max. | Min. | Typ. | Max. | Min. | Max. | |
| I_L Quiescent current | HCC types | 0/ 5 | | | 5 | | 1 | | 0.02 | 1 | | 30 | μA | |
| | | 0/10 | | | 10 | | 2 | | 0.02 | 2 | | 60 | | |
| | | 0/15 | | | 15 | | 4 | | 0.02 | 4 | | 120 | | |
| | | 0/20 | | | 20 | | 20 | | 0.04 | 20 | | 600 | | |
| | HCF types | 0/ 5 | | | 5 | | 4 | | 0.02 | 4 | | 30 | | |
| | | 0/10 | | | 10 | | 8 | | 0.02 | 8 | | 60 | | |
| | | 0/15 | | | 15 | | 16 | | 0.02 | 16 | | 120 | | |
| | | 0/ 5 | < 1 | 5 | 4.95 | | 4.95 | | | | | 4.95 | | |
| V_{OH} Output high voltage | 0/10 | < 1 | 10 | 9.95 | | 9.95 | | | | | | 9.95 | V | |
| | 0/15 | < 1 | 15 | 14.95 | | 14.95 | | | | | | 14.95 | | |
| | 5/0 | < 1 | 5 | | 0.05 | | | | 0.05 | | | 0.05 | | |
| V_{OL} Output low voltage | 10/0 | < 1 | 10 | | 0.05 | | | | 0.05 | | | 0.05 | V | |
| | 15/0 | < 1 | 15 | | 0.05 | | | | 0.05 | | | 0.05 | | |
| | 5/0.4/4.5 | < 1 | 5 | 4 | | 4 | | | | | | 4 | | |
| V_{IH} Input high voltage | 1/9 | < 1 | 10 | 8 | | 8 | | | | | | 8 | V | |
| | 1.5/13.5 | < 1 | 15 | 12.5 | | 12.5 | | | | | | 12.5 | | |
| | 4.5/0.5 | < 1 | 5 | | 1 | | | | 1 | | | 1 | | |
| V_{IL} Input low voltage | 9/1 | < 1 | 10 | | 2 | | | | 2 | | | 2 | V | |
| | 13.5/1.5 | < 1 | 15 | | 2.5 | | | | 2.5 | | | 2.5 | | |
| | 0/ 5 | 2.5 | | 5 | -8.4 | | -6.4 | -12.8 | | | | -4.6 | mA | |
| I_{OH} Output drive current | HCC types | 0/ 5 | 4.6 | | 5 | -2.1 | | -1.6 | -3.2 | | | -1.2 | | |
| | | 0/10 | 9.5 | | 10 | -6.25 | | -5 | -10 | | | -3.5 | | |
| | | 0/15 | 13.5 | | 15 | -24 | | -19 | -38 | | | -13 | | |
| | | 0/ 5 | 2.5 | | 5 | -6.8 | | -5.44 | -12.8 | | | -4.08 | | |
| | HCF types | 0/ 5 | 4.6 | | 5 | -1.7 | | -1.36 | -3.2 | | | -1.02 | | |
| | | 0/10 | 9.5 | | 10 | -5.31 | | -4.25 | -10 | | | -3.18 | | |
| | | 0/15 | 13.5 | | 15 | -20.18 | | -16.15 | -38 | | | -12.11 | | |
| | | 0/ 5 | 0.4 | | 5 | 2.1 | | 1.6 | 3.2 | | | 1.2 | | |
| I_{OL} Output sink current | HCC types | 0/10 | 0.5 | | 10 | 6.25 | | 5 | 10 | | | 3.5 | μA | |
| | | 0/15 | 1.5 | | 15 | 24 | | 19 | 38 | | | 13 | | |
| | | 0/ 5 | 0.4 | | 5 | 1.7 | | 1.36 | 3.2 | | | 1.02 | | |
| | HCF types | 0/10 | 0.5 | | 10 | 5.31 | | 4.25 | 10 | | | 3.18 | | |
| | | 0/15 | 1.5 | | 15 | 20.18 | | 16.15 | 38 | | | 12.11 | | |
| | | 0/18 | Any input | | 18 | | ± 0.1 | | $\pm 10^{-5}$ | ± 0.1 | | ± 1 | | |
| | | 0/15 | | | 15 | | ± 0.3 | | $\pm 10^{-5}$ | ± 0.3 | | ± 1 | | |
| C_I | Input capacitance | | Any input | | | | | | 15 | 22.5 | | | pF | |

* T_{Low} = - 55°C for HCC device; - 40°C for HCF device.* T_{High} = +125°C for HCC device; +85°C for HCF device.The Noise Margin for both "1" and "0" level is: 1V min. with $V_{DD} = 5V$
2V min. with $V_{DD} = 10V$
2.5V min. with $V_{DD} = 15V$

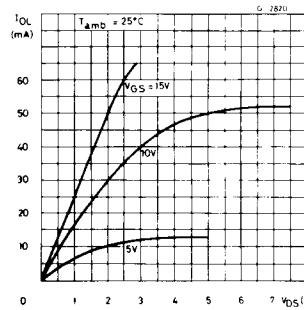
DYNAMIC ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^\circ C$, $C_L = 50 \text{ pF}$, $R_L = 200 \text{ k}\Omega$, typical temperature coefficient for all V_{DD} values is $0.3\%/\text{ }^\circ C$, all input rise and fall times = 20 ns)

| Parameter | Test conditions | Values | | | Unit |
|-------------------------------------------|-----------------|--------------------|------|------|------|
| | | $V_{DD}(\text{V})$ | Min. | Typ. | |
| t_{PLH}, t_{PHL} Propagation delay time | | 5 | 60 | 120 | ns |
| | | 10 | 35 | 70 | |
| | | 15 | 25 | 50 | |
| t_{THL}, t_{TLH} Transition time | | 5 | 40 | 80 | ns |
| | | 10 | 20 | 40 | |
| | | 15 | 15 | 30 | |

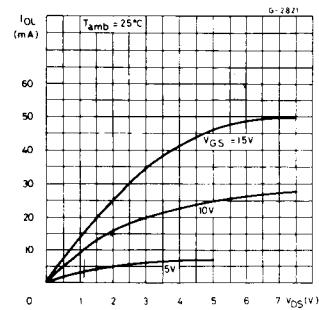
Minimum output high (source) current characteristics



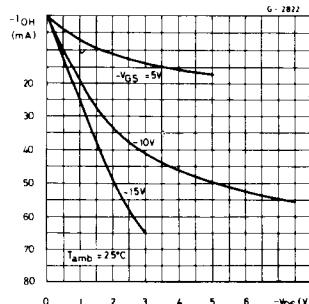
Typical output low (sink) current



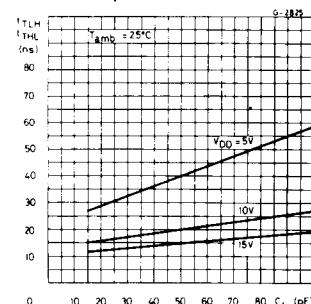
Minimum output low (sink) current characteristics



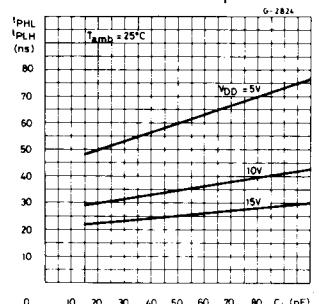
Typical output high (source) current characteristics



Typical transition time vs. load capacitance

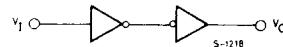
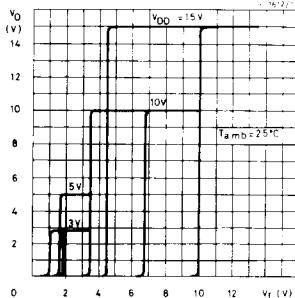


Typical propagation delay time vs. load capacitance

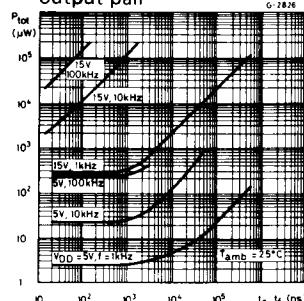


HCC/HCF 4041 UB

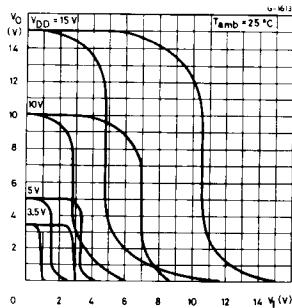
Minimum and maximum transfer characteristics—true output-and test circuit



Typical power dissipation vs. input rise and fall time per output pair



Minimum maximum transfer characteristics complement output-and test circuit



Typical power dissipation vs. frequency per output pair

